

# MICROPOSIT<sup>™</sup> MF<sup>™</sup>CD-26 DEVELOPER

Metal Ion Free - Non-Surfactant Developer

#### DESCRIPTION

MICROPOSIT MF CD-26 Developer is a 0.26N Surfactant Free product that offers high Photospeed and improved processing latitude for Conventional and Advanced Photoresists.

MF CD-26 is effective across various resist technologies including g/h/i line, KrF and ArF. MF CD-26 is a TMAH based Developer designed to be Metal Ion Free to avoid potential sources of Metal Ion Contamination.

MF CD-26 works well in Spray, Spray-Puddle, and Immersion processes.

#### **FEATURES**

- Low-foaming formulation
- Industry standard 0.26 Normality, surfactant free
- Improved contrast for optimal lithographic performance
- Uniform resist development with minimal bubble and residue related defects
- Effective across various resist technologies (g, g/h, i-Line, KrF, ArF

Low Unexposed Resist Loss (URL, or Dark Field Loss)

- Outstanding edge acuity
- High differential solubility
- Improved resist profiles

#### **Clean Efficient Development**

- No scumming
- Good resolution
- Wide process latitude
- Excellent exposure throughput

#### Lot to Lot Consistency

- Tight product specifications
- Total systems functional testing
- Statistical quality control

# MANUFACTURING PROCESS CONTROL

# Multiple Step In-process Testing

First In-process Test

Second In-process Test

TMAH Normality

Carbonate

TMAH Normality

Carbonate

Surface Tension

TMAH Normality

Packaging Approval\*

Carbonate

Particles

C of A\*\*



## \*Normality Controlled +/- 0.0002N \*\*Control to +/- 0.0018 TMAH

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### MICROPOSIT MF CD-26 Developer

#### Figure 2. Normality Control Chart MF CD-26



#### Instructions for Use

#### 1) Bath Make-up

MICROPOSIT MF CD-26 Developer is supplied ready to use and no bath make-up is required (there is no surfactant is the packaged product).

#### 2) Temperature

The recommended operation is between 15°C and 20°C +/- 1°C Photospeed does decrease as temperature increases although contrast and unexposed resist loss remains basically constant.

#### 3) <u>Time</u>

#### Immersion: 40-60 seconds

Spray & Puddle: Varies with equipment and application, Spray is typically 20-30 secs, Puddle process is 40-60 secs. Longer development times permit use of shorter exposure times. Shorter development times minimize Developer attack of the unexposed resist. Keeping the development constant and adjusting the exposure time as necessary to meet critical dimension requirements is recommended.

#### 4) Agitation

Immersion: Keep agitation mild and consistent.

Spray & Puddle: Agitation is not normally required for this application, some slight rotation at slow speed for a puddle process can be applied to help the development process especially dense features.

#### 5) <u>Rinse</u>

Immersion: A deionized water rinse is recommended using a cascade/overflow setup with rinsing continuing until desired resistivity is reached.

Spray & Puddle: An overlap deionized water rinse in conjunction with the developer cycle is recommended to prevent drying on the substrate surface.

#### 6) Bath Control

Immersion: For maximum process control, replace with a fresh bath at least once per shift (24 hours, also depends on wafer count), cover when not in use.

Spray & Puddle: Not Applicable

Batch Spray: As recommended by equipment manufacturer.

Figure 3. i-Line Lithographic Performance



168 mJ/cm<sup>2</sup> SPR955-CM/MF CD-26

MICROPOSIT MF CD-26 Developer

Figure 4. KrF Lithographic Performance

Figure 5. Surface Tension Comparison (with/without Surfactant)





140 nm 1:1 Trench



160 nm Isolated Line

| Recommended Process Conditions |   |  |
|--------------------------------|---|--|
| ARL                            | 600Å AR3 (205°C/60 sec.)                                |  |
| Film Thickness                 | 3,550Å  |  |
| Softbake                       | 130°C/60 sec.   |  |
| Post-exposure Bake             | 115°C/60 sec.   |  |
| Develop                        | MF <sup>∞</sup> CD-26 (0.26N),<br>45 sec. Single Puddle |  |

#### **STORAGE**

Store MICROPOSIT MF CD-26 Developer only in upright, original containers in a dry area at 10-25°c. Store away from acids, do not store in sunlight. Store away from heat and sources of ignition. Keep containers sealed when not in use, MF CD-26 Developer has a 24 month shelf life at recommended storage conditions.



#### HANDLING PRECAUTIONS CAUTION!

MICROPOSIT MF CD-26 Developer is an alkaline corrosive liquid containing tetramethyl ammonium hydroxide. Contact with eyes, skin and mucous membranes causes irritation and burns. Handle with care, do not get in eyes, on skin or on clothing. Avoid breathing vapours or mists. Use with adequate ventilation, wash thoroughly after handling. Wear suitable PPE when handling MICROPOSIT MF CD-26 Developer.

In case of eye or skin contact, flush affected areas with plenty of water for at least 15 minutes, then seek first aid help.

Please consult the Materials Safety Data Sheet prior to use.

#### WASTE TREATMENT

It is the end users responsibility to verify that the disposal of MICROPOSIT MF CD-26 Developer is in accordance with federal, state, and local law. The disposal of MICROPOSIT MF CD-26 Developer should also comply with all federal, state, and local environmental laws.



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| Marlborough, MA   | Tokyo                | Hong Kong           | Paris, France          |
| Tel: 800.832.6200 | Tel: +81.3.5213.2910 | Tel: +852.2680.6888 | Tel: +33.1.40.02.54.00 |
| Fax: 508.485.9113 | Fax: +81.3.5213.2911 | Fax: +852.2680.6333 | Fax: +33.1.40.02.54.07 |

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